

ABSTRACT OF THE DISCLOSURE

A semiconductor light emitting element and a semiconductor light emitting device, which are high in optical output, uniform in emission of light and high in production  
5 yield and productivity, comprise: an electrically conductive transparent substrate having a first surface and a second surface opposed to each other; a semiconductor epitaxial layer formed on a location of the first surface of the substrate; a first electrode formed on the semiconductor epitaxial layer;  
10 a second electrode formed on a location of the second surface of the substrate offset from alignment with the first electrode; and a groove formed to indent from the second surface of the substrate toward the first surface in a location between the first electrode and the second electrode.